## NSN 5962-01-273-8053

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View Online at https://aerobasegroup.com/nsn/5962-01-273-8053 **Body Length:** 0.840 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** 0.185 inches **Maximum Power Dissipation Rating:** 739.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Schottky and programmable and bipolar and 3-state output and high impedance **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Case Outline Source And Designator:** D-2 mil-m-38510

**Terminal Surface Treatment:** 

Solder

**Voltage Rating And Type Per Characteristic:** 

7.0 volts power source

**Time Rating Per Chacteristic:** 

75.00 nanoseconds propagation delay time, low to high level output and 75.00 nanoseconds propagation delay time, high to low level output

**Memory Device Type:** 

Rom

**Test Data Document:** 

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

**Terminal Type And Quantity:** 

16 printed circuit

Shelf Life:

N/a

**Unit Of Measure:** 

Demilitarization:

Yes - demil/mli

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